



Analog Devices Welcomes Hittite Microwave Corporation

NO CONTENT ON THE ATTACHED DOCUMENT HAS CHANGED



www.hittite.com

www.analog.com

THIS PAGE INTENTIONALLY LEFT BLANK



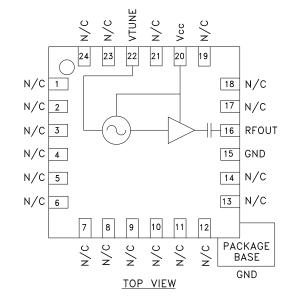


Typical Applications

Low noise MMIC VCO w/Buffer Amplifier for:

- 802.11a, HiperLAN WLAN
- VSAT, UNII & Microwave Radio
- Test Equipment & Industrial Controls
- Military

Functional Diagram



HMC429LP4 / 429LP4E

MMIC VCO w/ BUFFER AMPLIFIER, 4.45 - 5.0 GHz

Features

Pout: +4.0 dBm Phase Noise: -105 dBc/Hz @100 KHz No External Resonator Needed Single Supply: 3V @ 30 mA QFN Leadless SMT Package, 16 mm²

General Description

The HMC429LP4 & HMC429LP4E are GaAs InGaP Heterojunction Bipolar Transistor (HBT) MMIC VCOs with integrated resonators, negative resistance devices, varactor diodes, and buffer amplifiers. Covering 4.45 to 5.0 GHz, the VCO's phase noise performance is excellent over temperature, shock, vibration and process due to the oscillator's monolithic structure. Power output is 4.0 dBm typical from a single supply of 3.0V @ 30mA. The voltage controlled oscillator is packaged in a low cost leadless QFN 4x4 mm surface mount package.

Electrical Specifications, $T_{A} = +25^{\circ} C$, Vcc = +3V

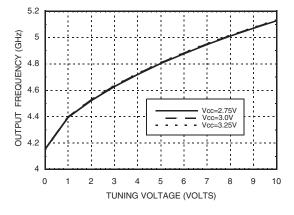
Parameter	Min.	Тур.	Max.	Units
Frequency Range		4.45 - 5.0		
Power Output	1.0	4.0		dBm
SSB Phase Noise @ 100 kHz Offset, Vtune= +5V @ RF Output		-105		dBc/Hz
Tune Voltage (Vtune)	0		10	V
Supply Current (Icc) (Vcc = +3.0V)		30		mA
Tune Port Leakage Current			10	μA
Output Return Loss		6		dB
Harmonics 2nd 3rd		-11 -23		dBc dBc
Pulling (into a 2.0:1 VSWR)		10		MHz pp
Pushing @ Vtune= +5V		14		MHz/V
Frequency Drift Rate		0.4		MHz/°C

For price, delivery, and to place orders, please contact Hittite Microwave Corporation: 20 Alpha Road, Chelmsford, MA 01824 Phone: 978-250-3343 Fax: 978-250-3373 Order On-line at www.hittite.com

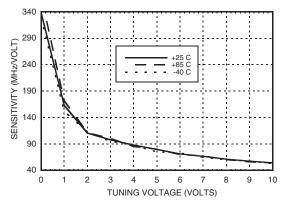




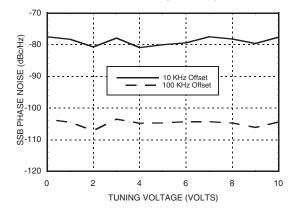
Frequency vs. Tuning Voltage, T= 25°C



Sensitivity vs. Tuning Voltage, Vcc= +3V

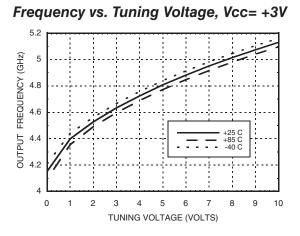


Phase Noise vs. Tuning Voltage

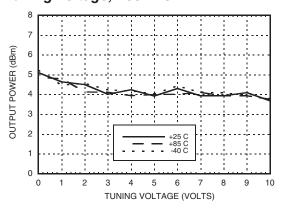


HMC429LP4 / 429LP4E

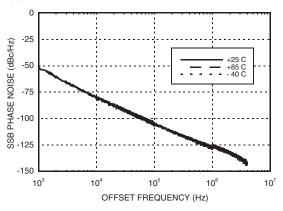
MMIC VCO w/ BUFFER AMPLIFIER, 4.45 - 5.0 GHz



Output Power vs. Tuning Voltage, Vcc= +3V



Typical SSB Phase Noise @ Vtune= +5V



For price, delivery, and to place orders, please contact Hittite Microwave Corporation: 20 Alpha Road, Chelmsford, MA 01824 Phone: 978-250-3343 Fax: 978-250-3373

Order On-line at www.hittite.com

VCOs & PLOs - SMT





HMC429LP4 / 429LP4E

MMIC VCO w/ BUFFER AMPLIFIER, 4.45 - 5.0 GHz

Absolute Maximum Ratings

Vcc	+3.5 Vdc
Vtune	0 to +11V
Channel Temperature	135 °C
Continuous Pdiss (T = 85°C) (derate 6.28 mW/°C above 85°C)	565 W
Storage Temperature	-65 to +150 °C
Operating Temperature	-40 to +85 °C



Outline Drawing

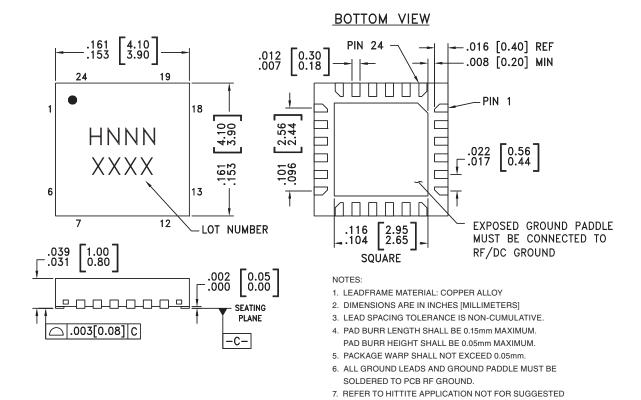
ELECTROSTATIC SENSITIVE DEVICE OBSERVE HANDLING PRECAUTIONS

Typical Supply Current vs. Vcc

Vcc (V)	Icc (mA)
2.75	21
3.0	30
3.25	38

Note: VCO will operate over full voltage range shown above.





Package Information

Part Nun	nber	Package Body Material	Lead Finish	MSL Rating	Package Marking ^[3]
HMC429	9LP4	Low Stress Injection Molded Plastic	Sn/Pb Solder	MSL1 ^[1]	H429 XXXX
HMC429I	LP4E	RoHS-compliant Low Stress Injection Molded Plastic	100% matte Sn	MSL1 ^[2]	<u>H429</u> XXXX

LAND PATTERN

[1] Max peak reflow temperature of 235 $^\circ\text{C}$

[2] Max peak reflow temperature of 260 °C

[3] 4-Digit lot number XXXX



HMC429LP4 / 429LP4E

MMIC VCO w/ BUFFER AMPLIFIER, 4.45 - 5.0 GHz



Pin Descriptions

Pin Number	Function	Description	Interface Schematic
1- 14, 17 - 19, 21, 23, 24	N/C	No Connection	
15	GND	This pin must be connected to RF & DC ground.	
16	RFOUT	RF output (AC coupled)	
20	Vcc	Supply Voltage Vcc= 3V	Vcco
22	VTUNE	Control Voltage Input. Modulation port bandwidth dependent on drive source impedance.	VTUNE \bigcirc
	GND	Package bottom has an exposed metal paddle that must be RF & DC grounded.	O GND =

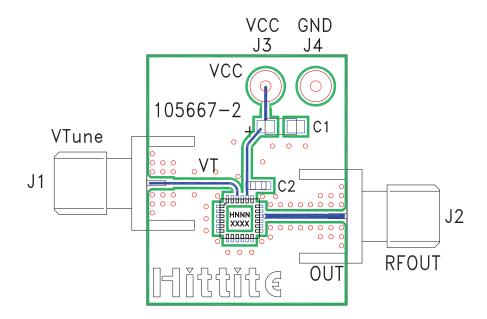




MMIC VCO w/ BUFFER AMPLIFIER, 4.45 - 5.0 GHz



Evaluation PCB



List of Materials for Evaluation PCB 105706 [1]

Item	Description	
J1 - J2	PCB Mount SMA RF Connector	
J3 - J4	DC Pin	
C1	4.7 µF Tantalum Capacitor	
C2	10,000 pF Capacitor, 0603 Pkg.	
U1	HMC429LP4 / HMC429LP4E VCO	
PCB [2]	105667 Eval Board	

[1] Reference this number when ordering complete evaluation PCB [2] Circuit Board Material: Rogers 4350

The circuit board used in the final application should use RF circuit design techniques. Signal lines should have 50 ohm impedance while the package ground leads and exposed paddle should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation circuit board shown is available from Hittite upon request.

For price, delivery, and to place orders, please contact Hittite Microwave Corporation: 20 Alpha Road, Chelmsford, MA 01824 Phone: 978-250-3343 Fax: 978-250-3373 Order On-line at www.hittite.com





HMC429LP4 / 429LP4E

MMIC VCO w/ BUFFER AMPLIFIER, 4.45 - 5.0 GHz

Notes: